## NSN 5962-01-371-1028

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Body Length:
1.060 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
0.185 inches
Maximum Power Dissipation Rating:
300.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
5895-01-305-8863
Features Provided:
Hermetically sealed and burn in and bipolar and programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
12 input
Case Outline Source And Designator:
D-8 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
12.0 volts power source
Time Rating Per Chacteristic:
75.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Pal
Test Data Document:
35351-168956 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
20 printed circuit
Shelf Life:
N/a

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**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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